

High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Very high switching speed

Application

- Electronic ballast for fluorescent lighting

Description

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA. The ST83003 is expressly designed for a new solution to be used in compact fluorescent lamps, where it is coupled with the ST93003, its complementary PNP transistor.

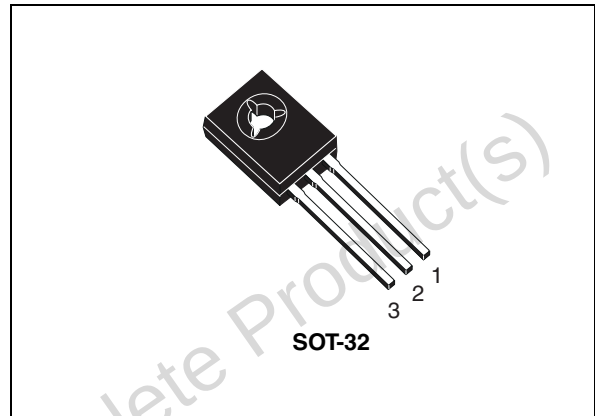


Figure 1. Internal schematic diagram

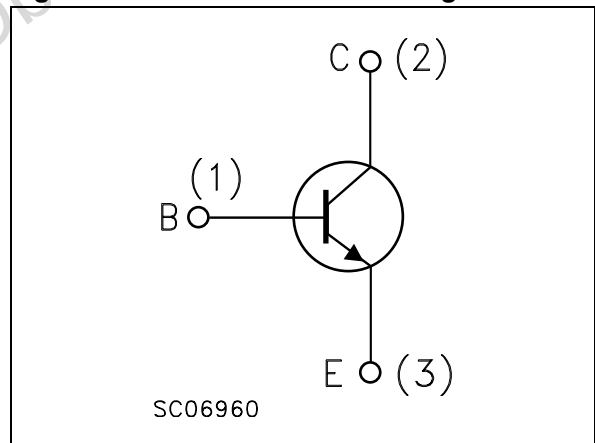


Table 1. Device summary

Order code	Marking	Package	Packaging
ST83003	83003	SOT-32	Bag

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Obsolete Product(s) - Obsolete Product(s)



1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage ($V_{BE} = 0$)	700	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V_{EBO}	Emitter-base voltage ($I_C = 0$, $I_B = 0.75$ A, $t_p < 10$ μ s)	$V_{(BR)EBO}$	V
I_C	Collector current	1.5	A
I_{CM}	Collector peak current ($t_p < 5$ ms)	3	A
I_B	Base current	0.75	A
I_{BM}	Base peak current ($t_p < 5$ ms)	1.5	A
P_{TOT}	Total dissipation at $T_c = 25$ °C	40	W
T_{STG}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Thermal resistance junction-case max	3.1	°C/W

2 Electrical characteristics

$T_{\text{case}} = 25\text{ °C}$ unless otherwise specified

Table 4. On/off states

Symbol	Parameter	Test conditions	Value			Unit
			Min.	Typ.	Max.	
I_{CES}	Collector cut-off current ($V_{\text{BE}} = 0$)	$V_{\text{CE}} = 700\text{ V}$			1	mA
		$V_{\text{CE}} = 700\text{ V}, T_{\text{C}} = 125\text{ °C}$			5	mA
$V_{(\text{BR})\text{EBO}}$	Emitter-base breakdown voltage ($I_{\text{C}} = 0$)	$I_{\text{E}} = 10\text{ mA}$	12		18	V
$V_{\text{CEO(sus)}}^{(1)}$	Collector-emitter sustaining voltage ($I_{\text{B}} = 0$)	$I_{\text{C}} = 10\text{ mA}$	400			V
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 0.5\text{ A}, I_{\text{B}} = 0.1\text{ A}$			0.5	V
		$I_{\text{C}} = 0.35\text{ A}, I_{\text{B}} = 50\text{ mA}$			1	V
$V_{\text{BE(sat)}}^{(1)}$	Base-emitter saturation voltage	$I_{\text{C}} = 0.5\text{ A}, I_{\text{B}} = 0.1\text{ A}$			1	V
$h_{\text{FE}}^{(1)}$	DC current gain	$I_{\text{C}} = 10\text{ mA}, V_{\text{CE}} = 5\text{ V}$	10	25	32	
		$I_{\text{C}} = 0.35\text{ A}, V_{\text{CE}} = 5\text{ V}$	16			
		$I_{\text{C}} = 1\text{ A}, V_{\text{CE}} = 5\text{ V}$	4			
t_{r}	Resistive load Rise time	$I_{\text{C}} = 0.35\text{ A}, V_{\text{CC}} = 125\text{ V},$ $I_{\text{B1}} = 70\text{ mA}, I_{\text{B2}} = -70\text{ mA}$ $t_{\text{P}} \geq 25\text{ }\mu\text{s}$ see Figure 14	1.5	100	2.9	ns
t_{s}	Storage time			2.2		μs
t_{f}	Fall time			0.2		μs
t_{s}	Inductive load Storage time	$I_{\text{C}} = 0.5\text{ A}, I_{\text{B1}} = 0.1\text{ A},$ $V_{\text{BE(off)}} = -5\text{ V},$ $L = 10\text{ mH}, V_{\text{clamp}} = 300\text{ V}$ see Figure 13		450		ns
				90		ns

1. Pulse test: pulse duration $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

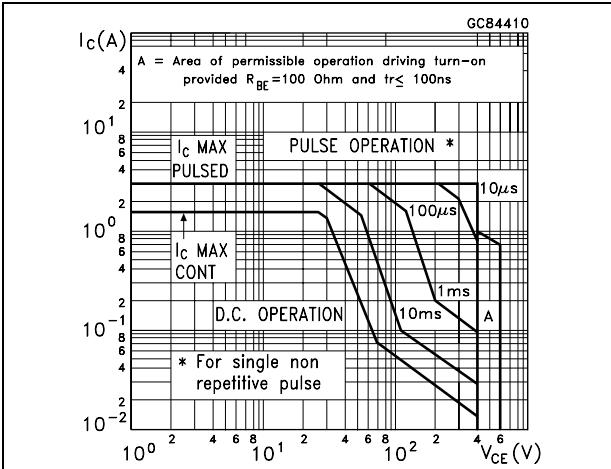


Figure 3. Derating

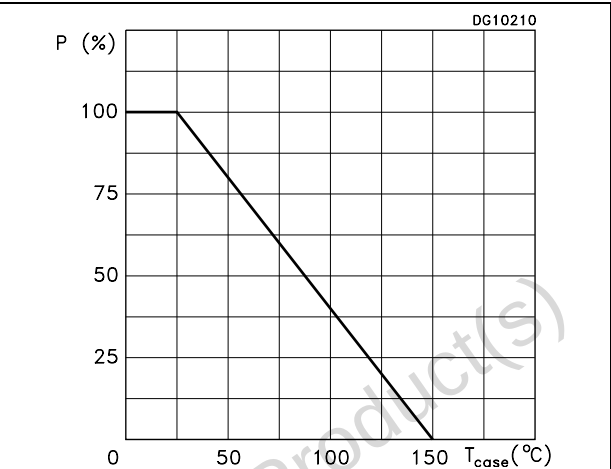


Figure 4. DC current gain ($V_{CE} = 5V$)

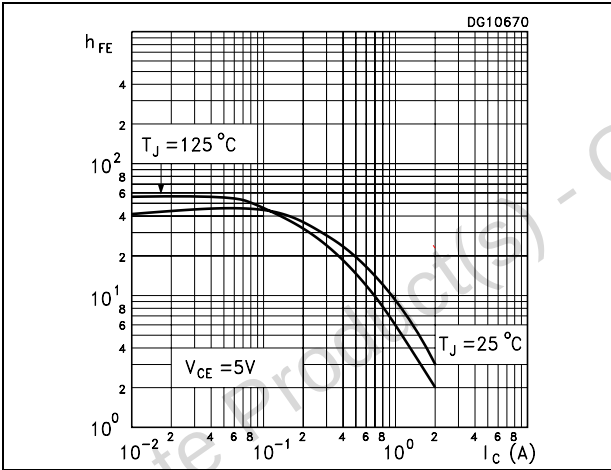


Figure 5. DC current gain ($V_{CE} = 1V$)

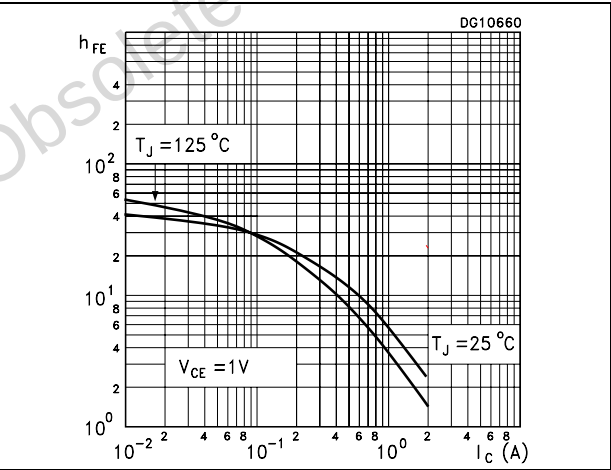


Figure 6. Collector emitter saturation voltage

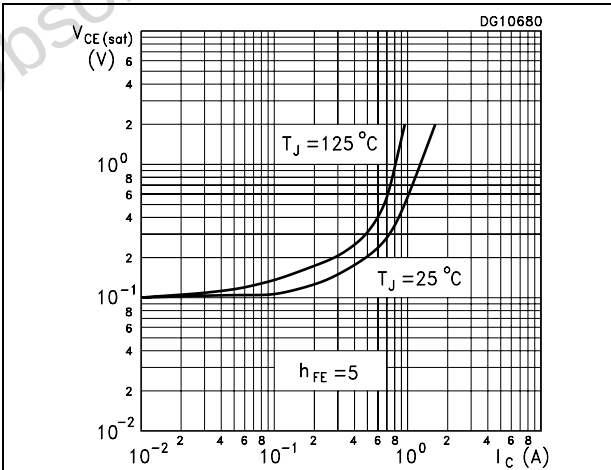


Figure 7. Base emitter saturation voltage

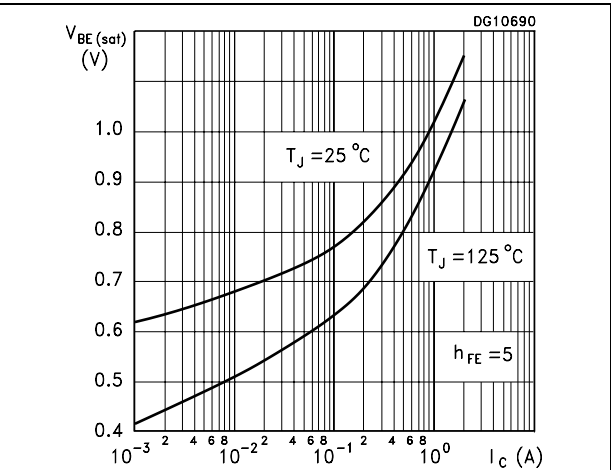


Figure 8. Resistive load fall time

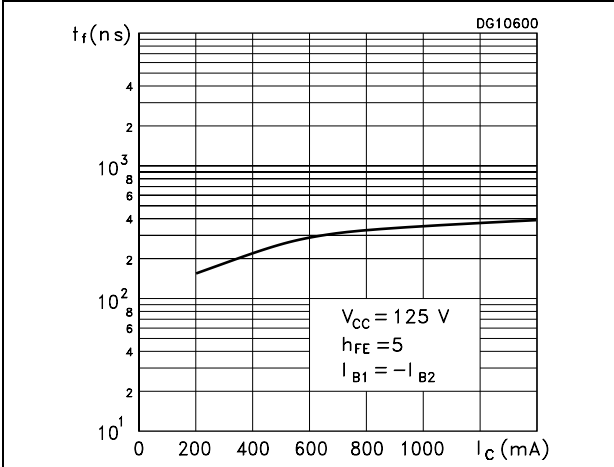


Figure 9. Resistive load storage time

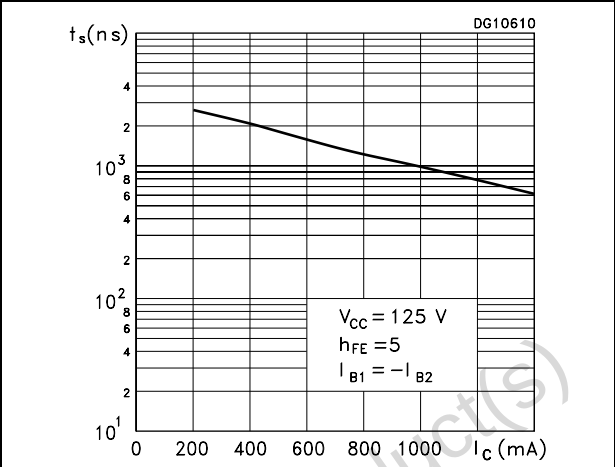


Figure 10. Inductive load fall time

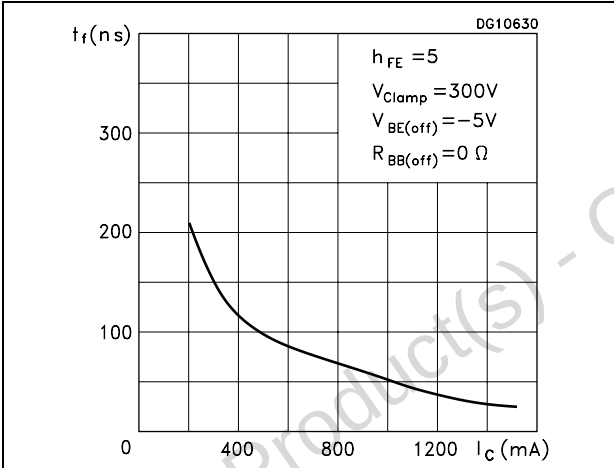


Figure 11. Inductive load storage time

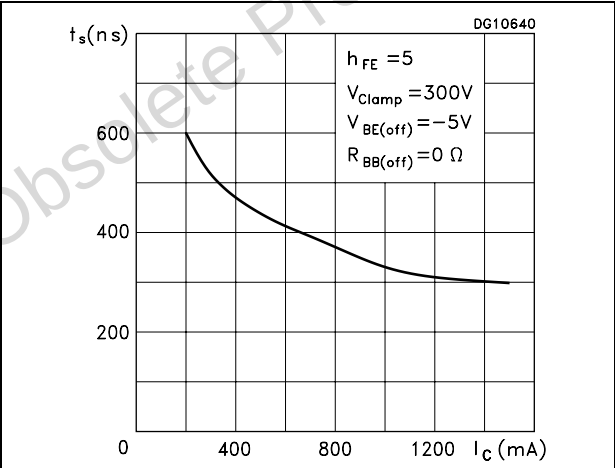
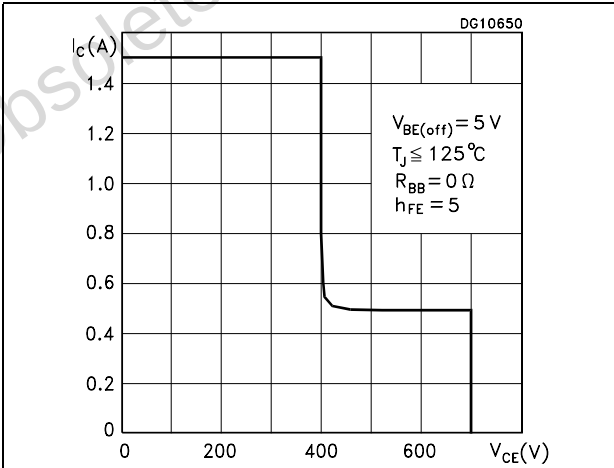
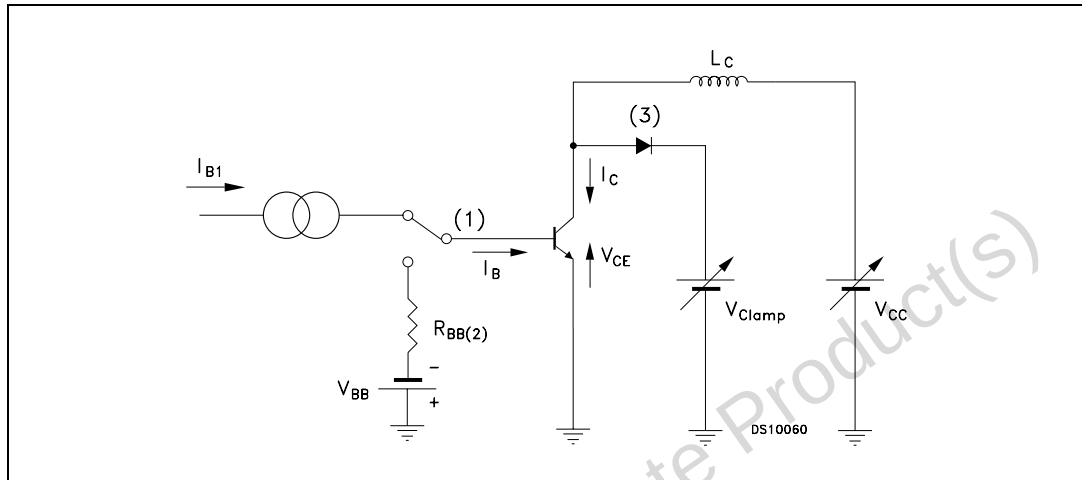


Figure 12. Reverse biased SOA



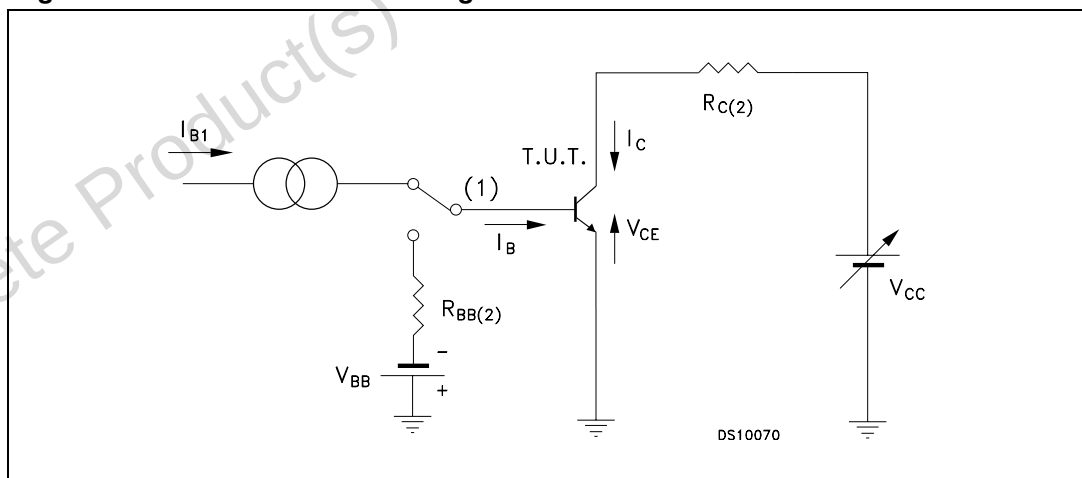
3 Test circuits

Figure 13. Inductive load switching



1. Fast electronic switch
2. Non-inductive resistor
3. Fast recovery rectifier

Figure 14. Resistive load switching



1. Fast electronic switch
2. Non-inductive resistor

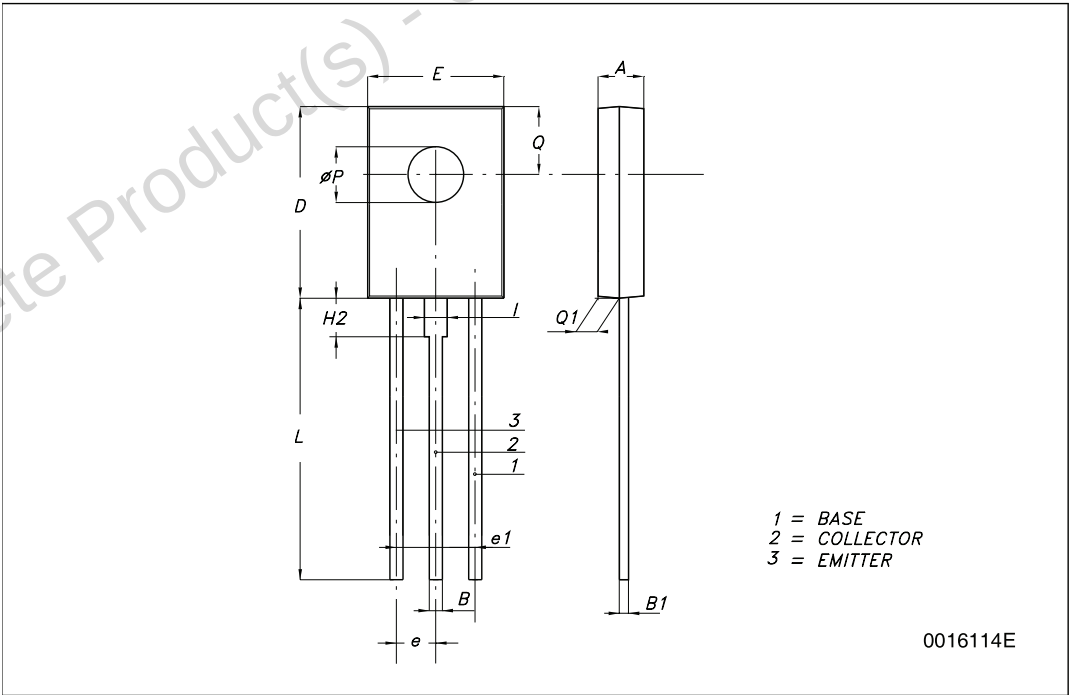
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Obsolete Product(s) - Obsolete Product(s)

SOT-32 (TO-126) MECHANICAL DATA

DIM.	mm.		
	MIN.	TYP	MAX.
A	2.4		2.9
B	0.64		0.88
B1	0.39		0.63
D	10.5		11.05
E	7.4		7.8
e	2.04	2.29	2.54
e1	4.07	4.58	5.08
L	15.3		16
P	2.9		3.2
Q		3.8	
Q1	1		1.52
H2		2.15	
I		1.27	



5 Revision history

Table 5. Document revision history

Date	Revision	Changes
16-Oct-2002	1	Initial release
08-Jul-2008	2	Mechanical data has been updated
08-Sep-2009	3	Updated packaging information Table 1 on page 1 .
03-Dec-2010	4	Added Table 3: Thermal data on page 3 .

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